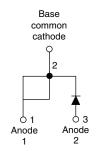


Vishay High Power Products

HEXFRED® Ultrafast Soft Recovery Diode, 8 A





TO-247AC modified

| PRODUCT SUMMARY | | | | |
|--|----------|--|--|--|
| V _R | 600 V | | | |
| V _F at 8 A at 25 °C | 1.7 V | | | |
| I _{F(AV)} | 8 A | | | |
| t _{rr} (typical) | 18 ns | | | |
| T _J (maximum) | 150 °C | | | |
| Q _{rr} (typical) | 65 nC | | | |
| dl _{(rec)M} /dt (typical) at 125 °C | 210 A/μs | | | |
| I _{RRM} (typical) | 3.5 A | | | |

FEATURES

- · Ultrafast recovery
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- · Specified at operating conditions
- · Lead (Pb)-free
- · Designed and qualified for industrial level

BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- · Higher frequency operation
- · Reduced snubbing
- · Reduced parts count

DESCRIPTION

HFA08PB60 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 8 A continuous current, the HFA08PB60 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA08PB60 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

| ABSOLUTE MAXIMUM RATINGS | | | | | |
|--|-----------------------------------|-------------------------|---------------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Cathode to anode voltage | V _R | | 600 | V | |
| Maximum continuous forward current | I _F | T _C = 100 °C | 8 | | |
| Single pulse forward current | I _{FSM} | | 60 | А | |
| Maximum repetitive forward current | I _{FRM} | | 24 | | |
| Maximum nawar dissination | P_{D} | T _C = 25 °C | 36 | W | |
| Maximum power dissipation | | T _C = 100 °C | 14 |] | |
| Operating junction and storage temperature range | T _J , T _{Stg} | | - 55 to + 150 | °C | |

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^{*} Pb containing terminations are not RoHS compliant, exemptions may apply

HFA08PB60PbF

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| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|--|---|--|------------|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| Cathode to anode breakdown voltage | V_{BR} | Ι _R = 100 μΑ | | 600 | - | - | |
| | | I _F = 8.0 A | | - | 1.4 | 1.7 | V |
| Maximum forward voltage | V_{FM} | I _F = 16 A | See fig. 1 | - | 1.7 | 2.1 | |
| | | I _F = 8.0 A, T _J = 125 °C | | - | 1.4 | 1.7 | |
| Maximum reverse | | V _R = V _R rated | See fig. 2 | - | 0.3 | 5.0 | |
| leakage current | $T_{J} = 125 ^{\circ}\text{C}, V_{R} = 0.8 \text{x} \text{V}_{R} \text{rated}$ See fig. 2 | See lig. 2 | - | 100 | 500 | μΑ | |
| Junction capacitance | C _T | V _R = 200 V | See fig. 3 | = | 10 | 25 | pF |
| Series inductance | L _S | Measured lead to lead 5 mm from package body - 8.0 | | - | nΗ | | |

| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|---|---------------------------|--|--|------|------|------|-------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| | t _{rr} | $I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$ | | - | 18 | - | |
| Reverse recovery time See fig. 5, 10 | t _{rr1} | T _J = 25 °C | 5 °C °C 5 °C I _F = 8.0 A dI _F /dt = 200 A/μs V _R = 200 V | - | 37 | 55 | ns |
| 000 lig. 0, 10 | t _{rr2} | T _J = 125 °C | | - | 55 | 90 | |
| Peak recovery current | I _{RRM1} | T _J = 25 °C | | - | 3.5 | 5.0 | - A - nC |
| See fig. 6 | I _{RRM2} | T _J = 125 °C | | - | 4.5 | 8.0 | |
| Reverse recovery charge | Q _{rr1} | T _J = 25 °C | | - | 65 | 138 | |
| See fig. 7 | Q _{rr2} | T _J = 125 °C | | - | 124 | 360 | |
| Peak rate of recovery current during t _b See fig. 8 | dI _{(rec)M} /dt1 | T _J = 25 °C | | - | 240 | - | Δ/μο |
| | dI _{(rec)M} /dt2 | T _J = 125 °C | | - | 210 | _ | A/μs |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|---|-------------------|--|--------------|-------|------------|------------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Lead temperature | T _{lead} | 0.063" from case (1.6 mm) for 10 s | - | - | 300 | °C |
| Thermal resistance, junction to case | $R_{	heta JC}$ | | - | - | 3.5 | |
| Thermal resistance, junction to ambient | $R_{	heta JA}$ | Typical socket mount | - | - | 40 | K/W |
| Thermal resistance, case to heatsink | $R_{\theta CS}$ | Mounting surface, flat, smooth and greased | - | 0.25 | - | |
| Weight | | | - | 6.0 | - | g |
| vveigni | | | - | 0.21 | - | oz. |
| Mounting torque | | | 6.0 (5.0) | - | 12 (10) | kgf · cm (lbf · in) |
| Marking device | | Case style TO-247AC modified (JEDEC) | | HFA08 | 3PB60 | |

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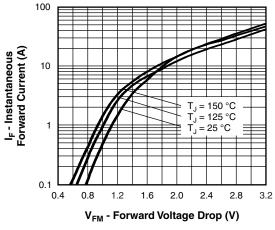


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

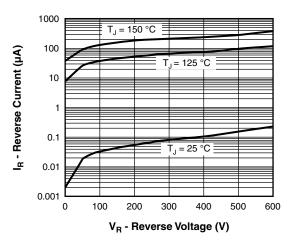


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

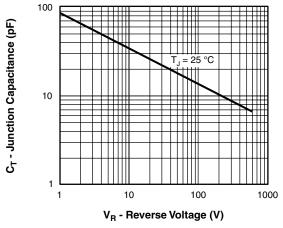


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

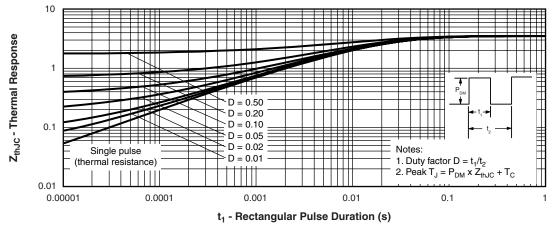


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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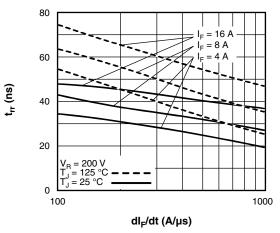


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt (Per Leg)

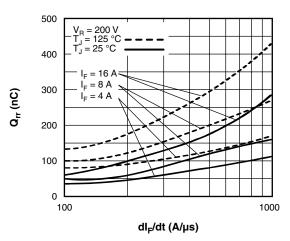


Fig. 7 - Typical Stored Charge vs. dl_F/dt (Per Leg)

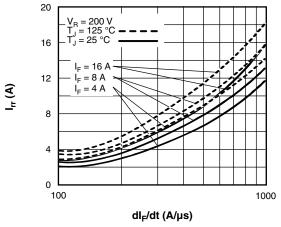


Fig. 6 - Typical Recovery Current vs. dl_F/dt (Per Leg)

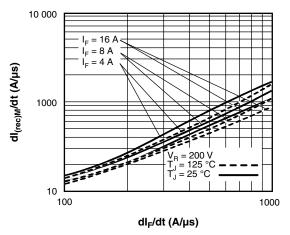


Fig. 8 - Typical $dI_{(rec)M}/dt$ vs. dI_F/dt (Per Leg)



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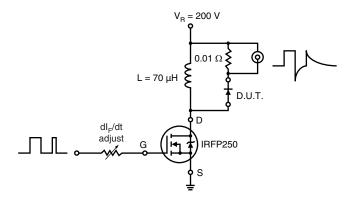
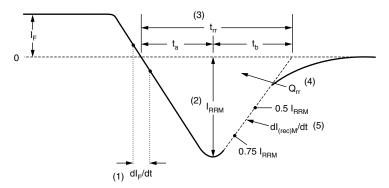


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) $\mathbf{Q}_{\rm rr}$ area under curve defined by $\mathbf{t}_{\rm rr}$ and $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

HFA08PB60PbF

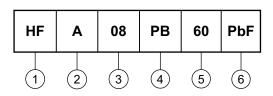
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ORDERING INFORMATION TABLE

Device code



1 - HEXFRED® family

Process designator: A = Electron irradiated

B = Platinum diffused

3 - Current rating (08 = 8 A)

- Package outline (PB = TO-247, 2 pins)

Voltage rating (60 = 600 V)

None = Standard production

• PbF = Lead (Pb)-free

| LINKS TO RELATED DOCUMENTS | | | | | |
|--|---------------------------------|--|--|--|--|
| Dimensions http://www.vishay.com/doc?95253 | | | | | |
| Part marking information | http://www.vishay.com/doc?95255 | | | | |

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